



MILITARY DATA SHEET

MN100371-X REV 0B0

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LOW POWER TRIPLE 4-INPUT MULTIPLEXER WITH ENABLE

General Description

The F100371 contains three 4-Input multiplexers which share a common decoder (inputs S0 and S1). Output buffer gates provide true and complement outputs. A HIGH on the Enable Input (E) forces all true outputs LOW (see Truth Table). All inputs have 50 ohm pull-down resistors.

Industry Part Number

100371

NS Part Numbers

100371DMQB
100371FMQB

Prime Die

F371

Processing

MIL-STD-883, Method 5004

Quality Conformance Inspection

MIL-STD-883, Method 5005

Subgrp	Description	Temp (°C)
1	Static tests at	+25
2	Static tests at	+125
3	Static tests at	-55
4	Dynamic tests at	+25
5	Dynamic tests at	+125
6	Dynamic tests at	-55
7	Functional tests at	+25
8A	Functional tests at	+125
8B	Functional tests at	-55
9	Switching tests at	+25
10	Switching tests at	+125
11	Switching tests at	-55

Features

- 35% power reduction of the 100171
- 2000V ESD protection
- Pin/function compatible with 100171
- Voltage compensated operating range= -4.2V to -5.7V
- Available to industrial grade temperature range

(Absolute Maximum Ratings)

(Note 1)

Storage Temperature (Tstg)	-65C to +150C
Maximum Junction Temperature (Tj)	
Ceramic	+175C
Plastic	+150C
Vee Pin Potential to Ground Pin	
	-7.0V to +0.5V
Input Voltage (DC)	
	Vee to +0.5V
Output Current (DC Output HIGH)	
	-50 mA
ESD	
(Note 2)	≥2000V

Note 1: Absolute maximum ratings are those values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: ESD testing conforms to MIL-STD-883, Method 3015.

Recommended Operating Conditions

Case Temperature (Tc)	
Commercial	0 C to +85 C
Industrial	-40 C to +85C
Military	-55C to +125C
Supply Voltage (Vee)	
	-5.7V to -4.2V

Electrical Characteristics

DC PARAMETERS

(The following conditions apply to all the following parameters, unless otherwise specified.)

DC: Vee Range: -4.2V to -5.7V, Tc=-55C to +125C, VCC=VCCA=GND

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
IIH(1)	Input HIGH Current	VEE=-5.7V, VM=-0.87V	1, 3	IN		340	uA	1, 2
			1, 3	IN		490	uA	3
IIH(2)	Input HIGH Current	VEE=-5.7V, VM=-0.87V	1, 3	Sn, $\bar{E}$		300	uA	1, 2
			1, 3	Sn, $\bar{E}$		450	uA	3
IIL	Input Low Current	VEE=-4.2V, VM=-1.83V	1, 3	INPUTS	0.5		uA	1, 2, 3
VOH	Output HIGH Voltage	VEE=-4.2V/-5.7V, VIH=-0.87V, VIL=-1.83V, LOADING: 50 Ohms to -2.0V	1, 3	OUTPUTS	-1025	-870	mV	1, 2
			1, 3	OUTPUTS	-1085	-870	mV	3
VOL	Output LOW Voltage	Vee=-4.2V/-5.7V, VIH=-0.87V, VIL=-1.83V, LOADING: 50 Ohms to -2.0V	1, 3	OUTPUTS	-1830	-1620	mV	1, 2
			1, 3	OUTPUTS	-1830	-1555	mV	3
VOHC	Output HIGH Voltage Corner Point High	Vee=-4.2V/-5.7V, VIH=-1.165V, VIL=-1.475V, Loading: 50 Ohms to -2.0V	1, 3	OUTPUTS	-1035		mV	1, 2
			1, 3	OUTPUTS	-1085		mV	3
VOLC	Output LOW Voltage Corner Point High	Vee=-4.2V/-5.7V, VIH=-1.165V, VIL=-1.475V, LOADING: 50 Ohms to -2.0V	1, 3	OUTPUTS		-1610	mV	1, 2
			1, 3	OUTPUTS		-1555	mV	3
VIH	Input HIGH Voltage		1, 3, 7	INPUTS	-1165	-870	mV	1, 2, 3
VIL	Input LOW Voltage		1, 3, 7	INPUTS	-1830	-1475	mV	1, 2, 3
IEE	Input LOW Voltage	VEE=-4.2/-5.7V	1, 3	INPUTS	-80	-30	mA	1, 2, 3

Electrical Characteristics

AC PARAMETERS

(The following conditions apply to all the following parameters, unless otherwise specified.)
AC: VEE Range: -4.2V to -5.7V, LOADING: 50 Ohms to -2.0V, VCC=VCCA=GND

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
tPLH/tPHL(1)	Propagation Delay	VEE=-4.2/-5.7V	2, 4	In to $\overline{Qn/Qn}$	0.2	1.7	ns	9
			2, 4	In to $\overline{Qn/Qn}$	0.2	2.0	ns	10
			2, 4	In to $\overline{Qn/Qn}$	0.1	1.9	ns	11
tPLH/tPHL(2)	Propagation Delay	VEE=-4.2/-5.7V	2, 4	Sn to $\overline{Qn/Qn}$	0.6	2.4	ns	9
			2, 4	Sn to $\overline{Qn/Qn}$	0.5	2.9	ns	10
			2, 4	Sn to $\overline{Qn/Qn}$	0.4	2.7	ns	11
tPLH/tPHL(3)	Propagation Delay	VEE=-4.2/-5.7V	2, 4	$\overline{E}$ to $\overline{Qn/Qn}$	0.6	2.4	ns	9
			2, 4	$\overline{E}$ to $\overline{Qn/Qn}$	0.5	2.9	ns	10
			2, 4	$\overline{E}$ to $\overline{Qn/Qn}$	0.5	2.7	ns	11
tTLH/tTHL	Transistion Time	VEE=-4.2/-5.7V	6	$\overline{Qn/Qn}$	0.3	1.5	ns	9
			6	$\overline{Qn/Qn}$	0.2	1.6	ns	10, 11

Note 1: Screen tested 100% on each device at -55 C, +25 C and +125 C temp., subgroups 1, 2, 3, 7 & 8.

Note 2: Screen tested 100% on each device at +25 C temp only, subgroup A9.

Note 3: Sample tested (Method 5005, Table 1) on each MFG. lot at +25 C, +125 C & -55 C temp., subgroups A1, 2, 3, 7 & 8.

Note 4: Sample tested (Method 5005, Table 1) on each MFG. lot at +25 C, subgroup A9, and at +125 C & -55 C temp., subgroups A10 & 11.

Note 5: Sample tested (Method 5005, Table 1) on each MFG. lot at +25 C temp. only, subgroup A9.

Note 6: Not tested at +25 C, +125 C & -55 C temp. (DESIGN CHARACTERIZATION DATA).

Note 7: Guaranteed by applying specified input condition and testing VOH/VOL.

Graphics and Diagrams

GRAPHICS#	DESCRIPTION
J24ERJ	CERDIP (J), 24LD .400 CENTERS (P/P DWG)
P000092A	CERDIP (J), 24LD .400 CENTERS (PIN OUT)
P000093A	CERPAC, QUAD, 24 LEAD (PIN OUT)
W24BRE	CERPAC, QUAD, 24 LEAD (P/P DWG)

See attached graphics following this page.

